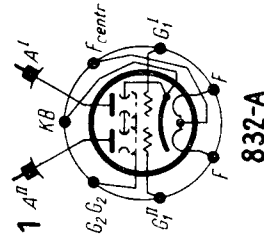
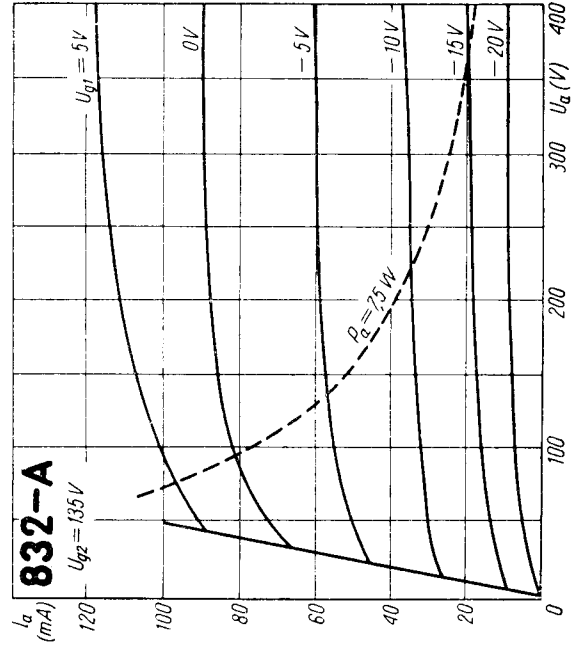


T.	Image	Image	Cl.	f MHz	U _a V	U _{g2} V	U _{g1} V	I _a × 2 mA	I _{g2} mA	I _{g1} × 2 mA	U _{g1/g1} V (≈)	P _{dr} mW	P _o W	P _{g2} W	P _a × 2											
															W	W										
832-A	int	1	C-Tgr	200	500	200	65	36	14	1,3	150	500	26	5	5	CCS										
																	200	750	24	15	1,4	150	600	26	5	CCS
																	250	750	32	12	0,9	140	800	18	7	ICAS
																	200	750	45	max	3	maximum	5	7,5	CCS	
																	250	750	57	max	3	maximum	5	8	ICAS	
																	200	425	26	60	1,2	140	500	16	3	CCS
																	200	600	18	65	1,3	150	500	17	2,3	CCS
																	250	600	30	70	1,5	160	700	26	4	ICAS
																	200	600	38	175	3	maximum	3,4	5	CCS	
																	250	600	48	175	3	maximum	5	6	ICAS	
			stat	250	135	10	30																			

S = 3,5 mA/V; μ_(g2/g1) = 6,5; U_{fil} = 100 V



C _{g1}	C _a	C _{g1/a}
pF	pF	pF
8	3,8	0,07

Equivalents

C 180	EEV	QQE 04/20	Phi
T-832	CCCP	QQV 04-15	Mul
TY-32	CCCP	RK 832 A	Ray
KΦ 2	CCCP	832	amer
P 2/12	SFR		

